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FDC655BN

Single N-Channel, Logic Level, PowerTrench® MOSFET 30 V, 6.3 A, 25 mΩ

Features

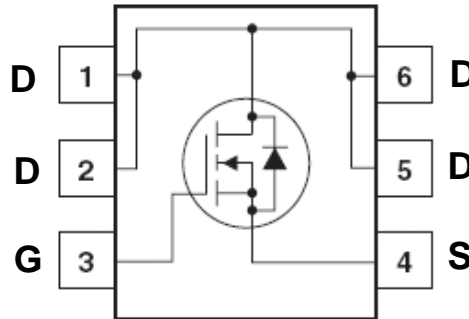
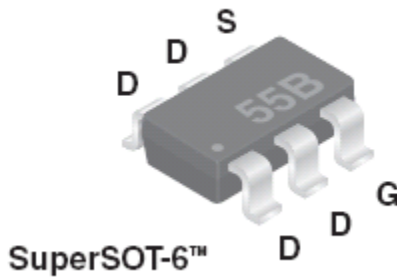
- Max $r_{DS(on)}$ = 25 mΩ at $V_{GS} = 10$ V, $I_D = 6.3$ A
- Max $r_{DS(on)}$ = 33 mΩ at $V_{GS} = 4.5$ V, $I_D = 5.5$ A
- Fast switching
- Low gate charge
- High performance technology for extremely low $r_{DS(on)}$
- Termination is Lead-free and RoHS Compliant



General Description

This N-Channel Logic Level MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

These devices are well suited for low voltage and battery powered applications where low in-line power loss and fast switching are required.



MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DS}	Drain to Source Voltage	30	V
V_{GS}	Gate to Source Voltage	± 20	V
I_D	-Continuous $T_A = 25^\circ\text{C}$ (Note 1a)	6.3	A
	-Pulsed	20	
P_D	Power Dissipation (Note 1a)	1.6	W
	Power Dissipation (Note 1b)	0.8	
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to + 150	$^\circ\text{C}$

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	78	$^\circ\text{C/W}$
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Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
.55B	FDC655BN	SSOT-6™	7"	8 mm	3000 units

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{ V}$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$, referenced to 25°C		25		mV/ $^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			± 100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	1	1.9	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$, referenced to 25°C		-5		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 6.3 \text{ A}$		21	25	m Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 5.5 \text{ A}$		26	33	
		$V_{GS} = 10 \text{ V}, I_D = 6.3 \text{ A}, T_J = 125^\circ\text{C}$		30	36	
g_{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_D = 6.3 \text{ A}$		35		S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1\text{MHz}$		470	620	pF
C_{oss}	Output Capacitance			100	130	pF
C_{rss}	Reverse Transfer Capacitance			60	90	pF
R_g	Gate Resistance			3.0		Ω

Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 15 \text{ V}, I_D = 1 \text{ A}, V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$		6	11	ns	
t_r	Rise Time			2	10	ns	
$t_{d(off)}$	Turn-Off Delay Time			15	26	ns	
t_f	Fall Time			2	10	ns	
Q_g	Total Gate Charge		$V_{GS} = 0 \text{ V to } 10 \text{ V}$	$V_{DD} = 15 \text{ V}, I_D = 6.3 \text{ A}$	9	13	nC
Q_g	Total Gate Charge		$V_{GS} = 0 \text{ V to } 5 \text{ V}$		5	7	nC
Q_{gs}	Gate to Source Charge		1.4			nC	
Q_{gd}	Gate to Drain "Miller" Charge		1.6			nC	

Drain-Source Diode Characteristics

I_S	Maximum Continuous Drain-Source Diode Forward Current			1.3	A
V_{SD}	Source-Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = 1.3 \text{ A}$ (Note 2)	0.8	1.2	V
t_{rr}	Reverse Recovery Time	$I_F = 6.3 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s}$	15	26	ns
Q_{rr}	Reverse Recovery Charge		4	10	nC

Notes:

1: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

- a. $78 \text{ }^\circ\text{C/W}$ when mounted on a 1 in^2 pad of 2 oz copper on FR-4 board.
- b. $156 \text{ }^\circ\text{C/W}$ when mounted on a minimum pad.

2: Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%.

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

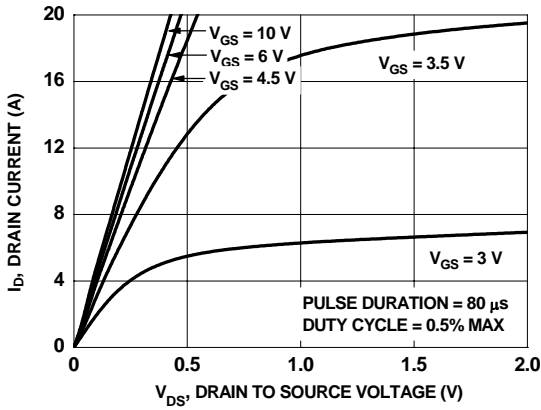


Figure 1. On Region Characteristics

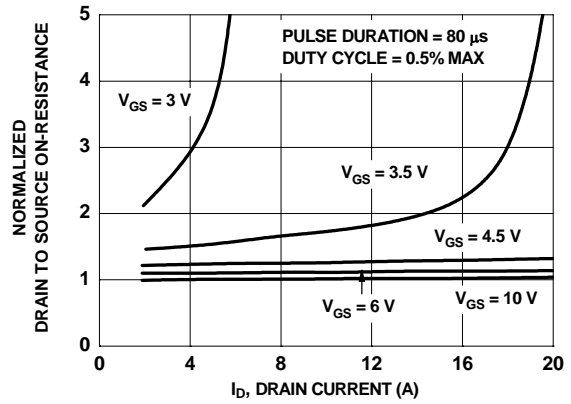


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

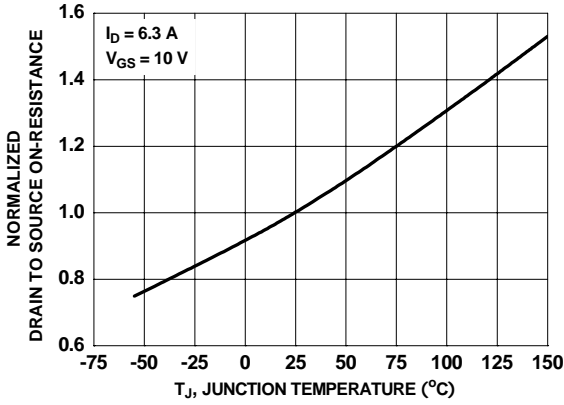


Figure 3. Normalized On Resistance vs Junction Temperature

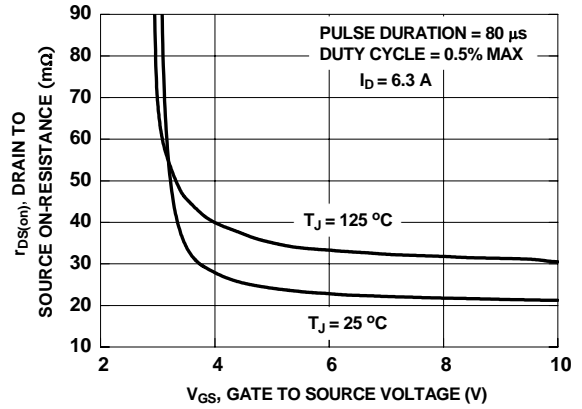


Figure 4. On-Resistance vs Gate to Source Voltage

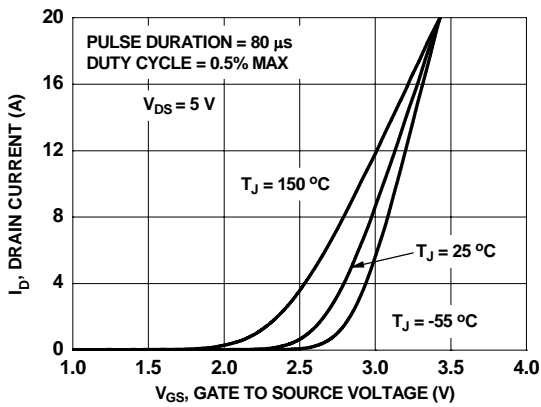


Figure 5. Transfer Characteristics

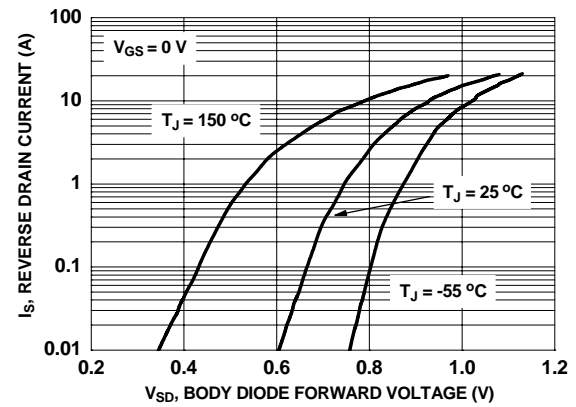


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

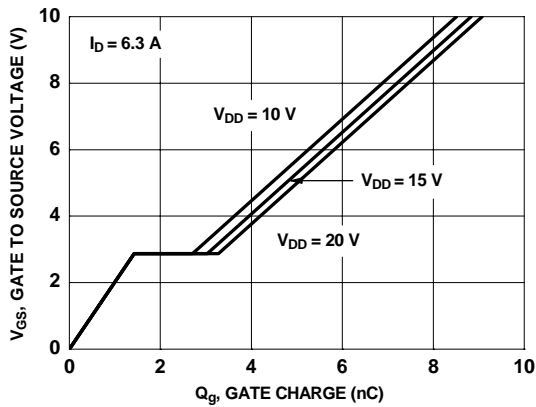


Figure 7. Gate Charge Characteristics

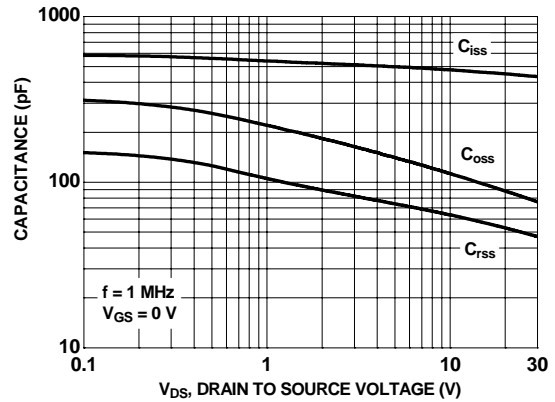


Figure 8. Capacitance vs Drain to Source Voltage

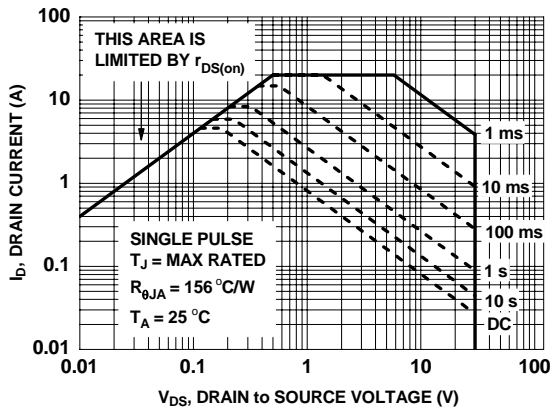


Figure 9. Forward Bias Safe Operating Area

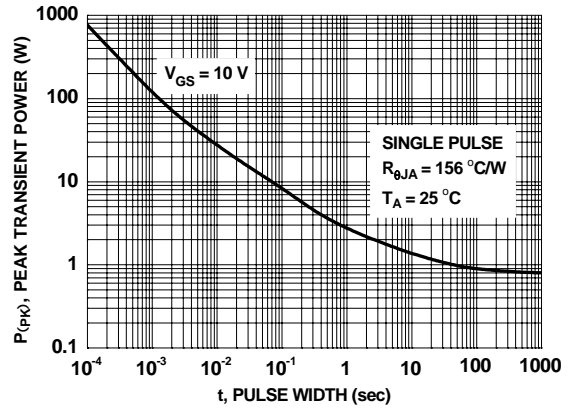


Figure 10. Single Pulse Maximum Power Dissipation

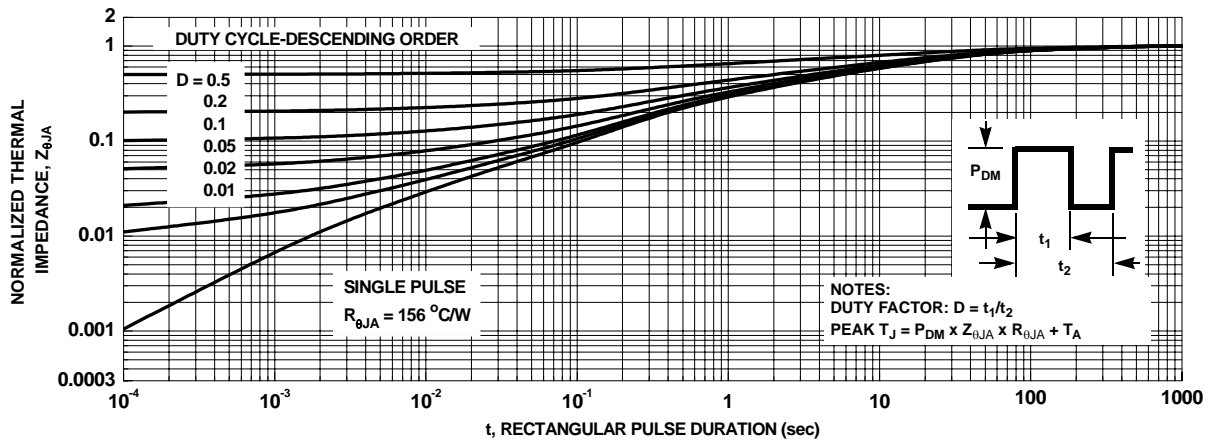




Figure 11. Junction-to-Ambient Transient Thermal Response Curve






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